

February 1984 Revised February 1999

MM74HC4316 Quad Analog Switch with Level Translator

General Description

The MM74HC4316 devices are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "ON" resistance and low "OFF" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Three supply pins are provided on the MM74HC4316 to implement a level translator which enables this circuit to operate with 0–6V logic levels and up to \pm 6V analog switch levels. The MM74HC4316 also has a common enable input in addition to each switch's control which when LOW will disable all switches to their OFF state. All analog inputs

and outputs and digital inputs are protected from electrostatic damage by diodes to $V_{\rm CC}$ and ground.

Features

- Typical switch enable time: 20 ns
- Wide analog input voltage range: ±6V
- Low "ON" resistance: 50 typ. $(V_{CC}-V_{EE}=4.5V)$ 30 typ. $(V_{CC}-V_{EE}=9V)$
- Low quiescent current: 80 µA maximum (74HC)
- Matched switch characteristics
- Individual switch controls plus a common enable

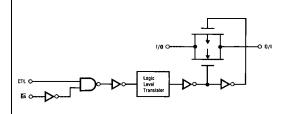
Ordering Code:

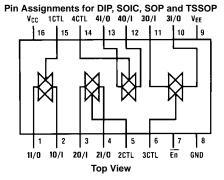
Order Number	Package Number	Package Description
MM74HC4316M	M16A	16-Lead Small Outline Integrated Package (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4316SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4316MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-1536, 4.4mm Wide
MM74HC4316N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Diagram

Connection Diagram





Truth Table

Inp	Switch			
En	CTL	I/O-O/I		
Н	Х	"OFF"		
L	L	"OFF"		
L	L L L H			

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Absolute Maximum Ratings(Note 1)

(Note 2)

Supply Voltage (V _{CC})	-0.5 to $+7.5$ V
Supply Voltage (V _{EE})	+0.5 to -7.5V
DC Control Input Voltage (V _{IN})	-1.5 to V_{CC} +1.5V
DC Switch I/O Voltage (V _{IO})	V_{EE} -0.5 to V_{CC} +0.5V
Clamp Diode Current (I _{IK} , I _{OK})	±20 mA
DC Output Current, per pin (I _{OUT})	±25 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±50 mA
Storage Temperature Range (T _{STG})	-65°C to +150°C
Power Dissipation (P _D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T _L)	
(Soldering 10 seconds)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
Supply Voltage (V _{EE})	0	-6	V
DC Input or Output Voltage			
(V_{IN}, V_{OUT})	0	V_{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) \ V_{CC} = 2.0V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
$V_{CC} = 12.0V$		250	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground. Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C.

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	VEE	V _{CC}	$T_A = 25^{\circ}C$		$T_A = -40 \text{ to } 85^{\circ}\text{C}$	$T_A = -55 \text{ to } 125^{\circ}\text{C}$	Units
Cymbol	i arameter	Conditions	*==	• 66	Тур		Guaranteed Limits		
V _{IH}	Minimum HIGH Level			2.0V		1.5	1.5	1.5	V
	Input Voltage			4.5V		3.15	3.15	3.15	V
				6.0V		4.2	4.2	4.2	V
V _{IL}	Maximum LOW Level			2.0V		0.5	0.5	0.5	V
	Input Voltage			4.5V		1.35	1.35	1.35	V
				6.0V		1.8	1.8	1.8	V
R _{ON}	Minimum "ON" Resistance	$V_{CTL} = V_{IH}$, $I_S = 2.0 \text{ mA}$	GND	4.5V	100	170	200	220	Ω
	(Note 5)	$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	40	85	105	110	Ω
		(Figure 1)	-6.0V	6.0V	30	70	85	90	Ω
			GND	2.0V	100	180	215	240	Ω
		$V_{CTL} = V_{IH}$, $I_S = 2.0 \text{ mA}$	GND	4.5V	40	80	100	120	Ω
		$V_{IS} = V_{CC}$ or V_{EE}	-4.5V	4.5V	50	60	75	80	Ω
		(Figure 1)	-6.0V	6.0V	20	40	60	70	Ω
R _{ON}	Maximum "ON" Resistance	V _{CTL} = V _{IH}	GND	4.5V	10	15	20	20	Ω
	Matching	$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	5	10	15	15	Ω
			-6.0V	6.0V	5	10	15	15	Ω
I _{IN}	Maximum Control	V _{IN} = V _{CC} or GND	GND	6.0V		±0.1	±1.0	±1.0	μΑ
	Input Current								
I _{IZ}	Maximum Switch "OFF"	$V_{OS} = V_{CC}$ or V_{EE}	GND	6.0V		±60	±600	±600	nA
	Leakage Current	$V_{IS} = V_{EE}$ or V_{CC}	-6.0V	6.0V		±100	±1000	±1000	nA
		V _{CTL} = V _{IL} (Figure 2)							
I _{IZ}	Maximum Switch "ON"	$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±40	±150	±150	nA
	Leakage Current	$V_{CTL} = V_{IH}, V_{OS} = OPEN$	-6.0V	6.0V		±60	±300	±300	nA
		(Figure 3)							
I _{CC}	Maximum Quiescent	V _{IN} = V _{CC} or GND	GND	6.0V		2.0	20	40	μΑ
	Supply Current	$I_{OUT} = 0 \mu A$	-6.0V	6.0V		8.0	80	160	μΑ

Note 4: For a power supply of 5V ±10% the worst case on resistances (R_{ON}) occurs for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} =5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V_{CC}-V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

AC Electrical Characteristics

 $V_{CC} = 2.0V-6.0V$, $V_{EE} = 0V-6V$, $C_L = 50$ pF (unless otherwise specified)

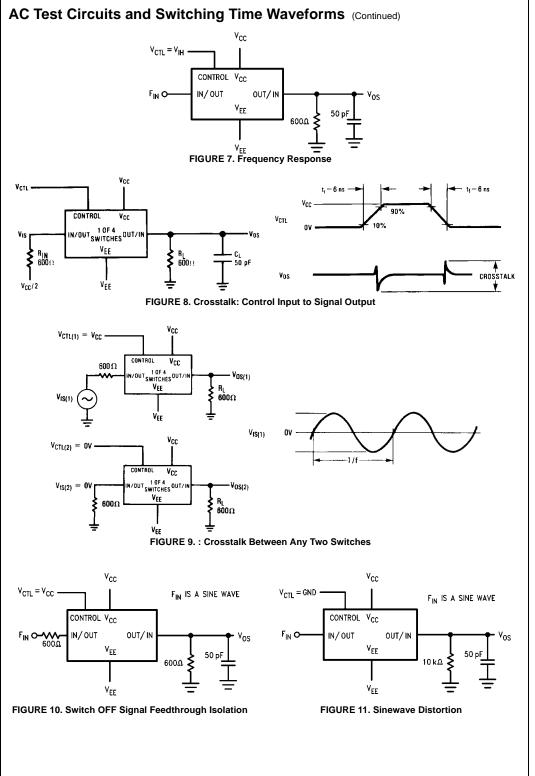
Symbol	Parameter	Conditions	V _{EE}	v _{cc}	$T_A = +25^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	$T_A = -55$ °C to $+125$ °C	Units
,					Тур	Typ Guaranteed Limits			
t _{PHL} ,	Maximum Propagation		GND	2.0V	25	50	63	75	ns
t_{PLH}	Delay Switch		GND	4.5V	5	10	13	15	ns
	In to Out		-4.5V	4.5V	4	8	12	14	ns
			-6.0V	6.0V	3	7	11	13	ns
t _{PZL} ,	Maximum Switch	$R_L = 1 k\Omega$	GND	2.0V	30	165	206	250	ns
t_{PZH}	Turn "ON" Delay		GND	4.5V	20	35	43	53	ns
	(Control)		-4.5V	4.5V	15	32	39	48	ns
			-6.0V	6.0V	14	30	37	45	ns
t _{PHZ} ,	Maximum Switch	$R_L = 1 k\Omega$	GND	2.0V	45	250	312	375	ns
t_{PLZ}	Turn "OFF" Delay		GND	4.5V	25	50	63	75	ns
	(Control)		-4.5V	4.5V	20	44	55	66	ns
			-6.0V	6.0V	20	44	55	66	
t _{PZL} ,	Maximum Switch		GND	2.0V	35	205	256	308	ns
t _{PZH}	Turn "ON" Delay		GND	4.5V	20	41	52	62	ns
1 211	(Enable)		-4.5V	4.5V	19	38	48	57	ns
	,		-6.0V	6.0V	18	36	45	54	ns
t _{PLZ} ,	Maximum Switch		GND	2.0V	58	265	330	400	ns
t _{PHZ}	Turn "OFF" Delay		GND	4.5V	28	53	67	79	ns
THZ	(Enable)		-4.5V	4.5V	23	47	59	70	ns
	(2.10510)		-6.0V	6.0V	21	47	59	70	ns
f	Minimum Frequency	$R_{I} = 600\Omega, V_{IS} = 2V_{PP}$	0.0 V	4.5	40		00	70	MHz
f _{MAX}	Response (Figure 7)	at (V _{CC} -V _{EE} /2)	-4.5V	4.5V	100				MHz
	20 log (V _{OS} /V _{IS})= -3 dB		-4.5 V	4.5 V	100				IVII IZ
	Control to Switch	$R_1 = 600\Omega$, $F = 1$ MHz	0V	4.5V	100				mV
	Feedthrough Noise	$C_1 = 50 \text{ pF}$	-4.5V		250				mV
	(Figure 8)	(Note 7) (Note 8)	-4.5 V	4.5 V	230				IIIV
	, ,	$R_1 = 600\Omega$, $F = 1$ MHz							<u> </u>
	Crosstalk Between	R _L = 60052, F = 1 MITZ	0) (4 = 1 /					
	any Two Switches		0V	4.5V	-52				dB
	(Figure 9)		-4.5V	4.5V	-50				dB
	Switch OFF Signal	$R_L = 600\Omega$, $F = 1 MHz$							
	Feedthrough Isolation	V _{CTL} = V _{IL} ,	0V	4.5V	-42				dB
	(Figure 10)	(Note 7) (Note 8)	-4.5V	4.5V	-44				dB
THD	Sinewave Harmonic	$R_L = 10 \text{ K}\Omega$, $C_L = 50 \text{ pF}$,							
	Distortion	F = 1 KHz							
	(Figure 11)	$V_{IS} = 4V_{PP}$		4.5V	0.013				%
		$V_{IS} = 8V_{PP}$	-4.5V	4.5V	0.008				%
C _{IN}	Maximum Control				5				pF
	Input Capacitance								
C _{IN}	Maximum Switch				35				pF
	Input Capacitance					<u> </u>			
C _{IN}	Maximum Feedthrough	V _{CTL} = GND			0.5				pF
	Capacitance								
C _{PD}	Power Dissipation				15				pF
	Capacitance								
		•———						•	-

Note 6: Adjust 0 dBm for F = 1 KHz (Null R_L/Ron Attenuation).

Note 7: V_{IS} is centered at $V_{CC} - V_{EE}/2$.

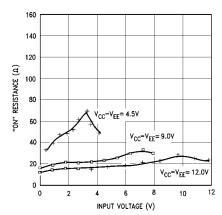
Note 8: Adjust for 0 dBm.

AC Test Circuits and Switching Time Waveforms Vcc 1 OF 4 Switches 1/0 VEE FIGURE 2. "OFF" Channel Leakage Current FIGURE 1. "ON" Resistance AMMETER 1 OF 4 SWITCHES $V_{1S} = V_{CC}$ TO GND V_{EE} FIGURE 3. "ON" Channel Leakage Current CONTROL VCC 1 OF 4 O. SWITCHES VEE FIGURE 4. $t_{\rm PHL}$, $t_{\rm PLH}$ Propagation Delay Time Signal Input to Signal Output tplz CONTROL 1 OF 4 O/ SWITCHES FIGURE 5. t_{PZL} , t_{PLZ} Propagation Delay Time Control to Signal Output tpzh tphz VCC 1/0 1 OF 4 SWITCHES VEE 1_{PH7} **V**OH FIGURE 6. t_{PZH} , t_{PHZ} Propagation Delay Time Control to Signal Output

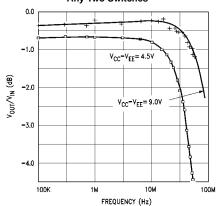


Typical Performance Characteristics

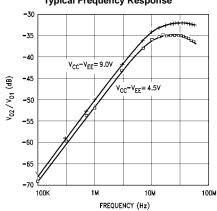
Typical "ON" Resistance



Typical Crosstalk Between **Any Two Switches**



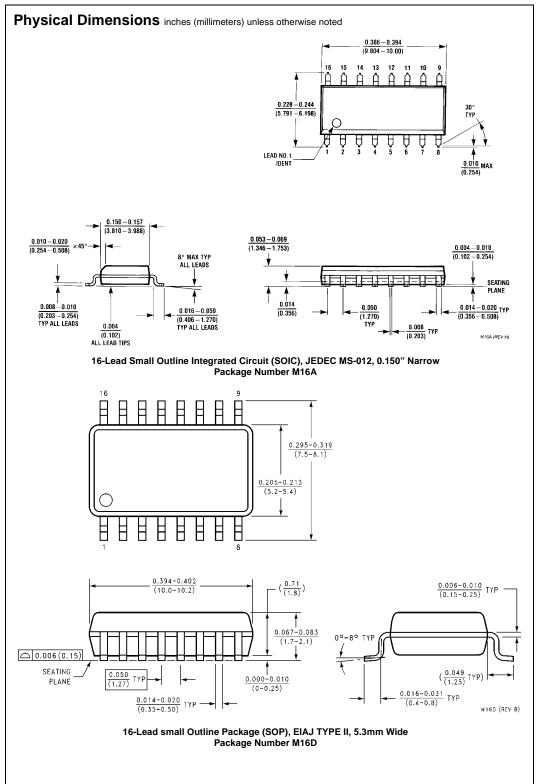
Typical Frequency Response



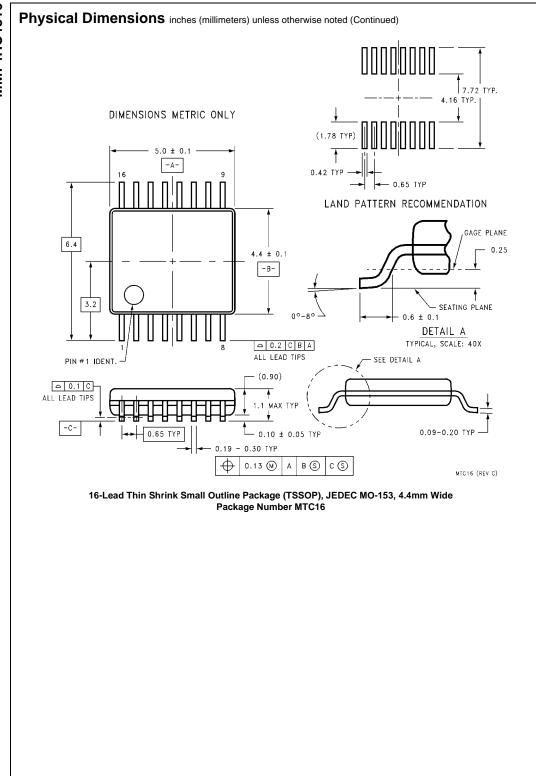
Special Considerations

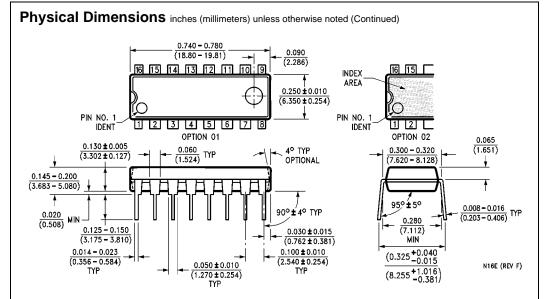
In certain applications the external load-resistor current may include both $\rm V_{CC}$ and signal line components. To avoid drawing $V_{\mbox{\footnotesize CC}}$ current when switch current flows into

the analog switch input pins, the voltage drop across the switch must not exceed 0.6V (calculated from the ON resis-



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16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N16E

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